

PN 3819	Nsc	N-FET	=2N3819: 0,36W	8b	TO-106				+2N3819
PN 4013...4014	Nsc	Si-N	=2N4013...4014: 0,625W	7e	TO-92				+2N4013...4014
PN 4054	New	Si-P	LFS-L: 50V, 4A, 25W, 0,8MHz	17j	TO-220	BD 244 C	17j		BD 244(A...C), BD 540(A...D), BD 536, ++
PN 4091...4093	Nsc	N-FET	=2N4091...4093: 0,36W	7f	TO-92				+2N4091...4093
PN 4121...4122	Fch,Nsc	Si-P	=2N4121...4122: 0,625W	7e	TO-92				+2N4121...4122
PN 4140...4143	Fch,Nsc	Si-N/P	=2N4140...4143: 0,625W	7e	TO-92				+2N4140...4143
PN 4220...4224	Nsc	N-FET	=2N4220...4224: 0,36W	7f	TO-92				+2N4220...4224
PN 4248...4250(A)	Fch,Nsc	Si-P	=2N4248...4250(A): 0,625W	7e	TO-92				+2N4248...4250(A)
PN 4257...4258(A)	Fch,Nsc	Si-P	=2N4257...4258(A): 0,625W	7e	TO-92				+2N4257...4258(A)
PN 4274...4275	Nsc	Si-N	=2N4274...4275: 0,625W	7e	TO-92				+2N4274...4275
PN 4302...4304	Nsc	N-FET	=2N4302...4304: 0,36W	7f	TO-92				+2N4302...4304
PN 4313	Fch,Nsc	Si-P	=2N4313: 0,625W	7e	TO-92				+2N4313
PN 4342...4343	Nsc	P-FET	=2N4342...4343: 0,35W	7b	TO-92				+2N4342...4343
PN 4354...4357	Fch,Nsc	Si-P	=2N4354...4357: 0,625W	7e	TO-92				+2N4354...4357
PN 4360	Nsc	P-FET	=2N4360: 0,35W	7b	TO-92				+2N4360
PN 4391...4393	Nsc	N-FET	=2N4391...4393: 0,36W	7f, 7d	TO-92	+2N4391...93			+2N4391...4393
PN 4416(A)	Nsc,Phi	N-FET	+2N4416(A): 0,36W	7f, 7d	TO-92				+2N4416(A)
PN 4423	Nsc	Si-P	+2N4423: 0,625	7e	TO-92				+2N4423
PN 4856...4861	Nsc	N-FET	=2N4856...4861: 0,36W	7f	TO-92				+2N4856...4861
PN 4888...4889	Fch	Si-P	=2N4888...4889: 0,625	7e	TO-92				+2N4888...4889
PN 4916...4917	Fch,Nsc	Si-P	=2N4916...4917: 0,625	7e	TO-92				+2N4916...4917
PN 4945...4946	Fch	Si-N	=2N4945...4946	7	TO-92				+2N4945...4946
PN 4965	Fch	Si-P	=2N4965	7	TO-92				+2N4965
PN 5033	Nsc	P-FET	=2N5033: 0,35	7b	TO-92				+2N5033
PN 5126...5137	Fch,Nsc,Mic	Si-N	=2N5126...5137: 0,625W	7e	TO-92				+2N5126...5137
PN 5138...5139	Fch,Nsc,Mic	Si-P	=2N5138...5139: 0,625W	7e	TO-92				+2N5138...5139
PN 5140...5143	Fch,Nsc	Si-P	=2N5140...5143: 0,625W	7e	TO-92				+2N5139...5139
PN 5163	Nsc	N-FET	=2N5163: 0,36W	7f	TO-92				+2N5163
PN 5179	Nsc	Si-N	=2N5179: 0,625W	7f	TO-92	+2N5179			+2N5179
PN 5415...5416	Phi	Si-P	=2N5415...5416: 0,625W	7e	TO-92	+2N5415...16			+2N5415...5416
PN 5447...5448	Nsc	Si-P	=2N5447...5448	7e	TO-92	+2N5447...48			+2N5447...5448
PN 5855...5858	Fch	Si-N/P	=2N5855...5858: 0,625W	7e	TO-92	+2N5855...58			+2N5855...5858
PN 5910	Fch,Nsc	Si-P	=2N5910: 0,625W	7e	TO-92				+2N5910
PN 5964...5965	Fch	Si-N	=2N5964...5965: 0,625W	7e	TO-92				+2N5964...65
PN 6076	Fch	Si-P	=2N6076	7	TO-92				+2N6076
PN 7055	Nsc	Si-N	Vid, 220/220V, 0,03A, 0,625W, >50MHz	7e	TO-92	BF 420 A	7c		BF 298...299, BF 420(A), BF 422(A), ++
PNA 7506(D)	Phi	A/D-IC	6 Bit, Video, 20MHz, NMOS/TTL compatible		18-MDIP				-
PNA 7507(A)	Phi	A/D-IC	7 Bit						-
PNA 7509 D	Phi	NMOS-A/D-IC	=PNA 7509N: SMD		24-MDIP				-
PNA 7509 N,P	Phi	NMOS-A/D-IC	7 Bit, Video, 22MHz, 0...+70°		24-DIP				-
PNA 7518 N,P	Phi	NMOS-D/A-IC	8 Bit, multiplying, 0...+70°		16-DIP				-
PO		Si-P	=2SA1712-O (SMD-Marking)	35	SOT-23				+2SA1712
PO		Si-N	=2SC2884-O (SMD-Marking)	39	SOT-89				+2SC2884
PO		MOS-P-FET-e	=2SJ212 (SMD-Marking)	39	SOT-89				+2SJ212
PO		Si-N	=BFP 90A (Marking)	51	SOT-173				+BFP 90A
PO		Si-P	=KRA113S (SMD-Marking)	35	SOT-23				+KRA 113S
PO		Si-N	=KTC4376-O (SMD-Marking)	39	SOT-89				+KTC 4376
PQ 6		Si-P	=PMBS 3906 (SMD-Marking)	35	SOT-23				+PMBS 3906
PQ 38	Mot	Si-N	Vid, 300V, 0,5A, 0,8W, >35MHz	2a	TO-39	(MPS-U10) ⁶	13m		(BF 461...462, BF 758...759, MPS-U10,++) ⁶
PQ 39	Mot	Si-P	Vid, 300V, 0,5A, 0,6W, >35MHz	2a	TO-39	(MPS-U60) ⁶	13m		(BF 464...465, BF 761...762, MPS-U60,++) ⁶
PP		MOS-P-FET-e	=2SJ213 (SMD-Marking)	39	SOT-89				+2SJ213
PP		Si-P	=KRA114S (SMD-Marking)	35	SOT-23				+KRA 114S
PQ		Si-N-Darl	=2SD1511-Q (SMD-Marking)	39	SOT-89				+2SD1511
PQ		Si-N	=2SD1821-Q (SMD-Marking)	35(2mm)	SOT-323				+2SD1821
PQ		Si-N	=2SD2240-Q (SMD-Marking)	35(1,6mm)	SS Mini				+2SD2240
PQ		Si-N	=2SD814-Q (SMD-Marking)	35	SOT-23				+2SD814
PQ		MOS-P-FET-e	=2SJ355 (SMD-Marking)	39	SOT-89				+2SJ355
PQ		Si-P	=KRA221S (SMD-Marking)	35	SOT-23				+KRA 221S
PR...PS									
PR		Si-P	=2SA1712-R (SMD-Marking)	35	SOT-23				+2SA1712
PR		Si-N-Darl	=2SD1511-R (SMD-Marking)	39	SOT-89				+2SD1511
PR		Si-N	=2SD1821-R (SMD-Marking)	35(2mm)	SOT-323				+2SD1821
PR		Si-N	=2SD2240-R (SMD-Marking)	35(1,6mm)	SS Mini				+2SD2240
PR		Si-N	=2SD814-R (SMD-Marking)	35	SOT-23				+2SD814
PR		MOS-P-FET-e	=2SJ356 (SMD-Marking)	39	SOT-89				+2SJ356
PR		Si-P	=KRA222S (SMD-Marking)	35	SOT-23				+KRA 222S
PR 1		Si-Di				1N4007	31a		
PR 121	Tho	Si-Di	FRr, 1200V, 1A, Uf<1,5V(1A), <500ns	31a	DO-15	BY 228	31a		BY 231/1200, BY 245/1200, BY 228, BY 458
PR 141	Tho	Si-Di	=PR 121: 1400V	31a	DO-15	BY 228	31a		BY 231/1400, BY 228, BY 448
PR 5400...5408	Itt	Si-Di	>1N5400...5408	31a	DO-27A	BY 255	31a		
PRF 540	Phi	MOS-N-FET-e	VFET, SMPS, 100V, 27A, 125W, <30/80ns	17p	TO-220				(BUZ 341, BUZ 349, 2SK851, 2SK906) ⁶
PRF 542	Phi	MOS-N-FET-e	VFET, SMPS, 100V, 24A, 125W, <30/80ns	17p	TO-220				(BUZ 341, BUZ 349, 2SK851, 2SK906) ⁶
PRF 640	Phi	MOS-N-FET-e	VFET, SMPS, 200V, 18A, 125W, <30/80ns	17p	TO-220				(BUZ 341, BUZ 350, 2SK851, 2SK901) ⁶
PRF 642	Phi	MOS-N-FET-e	VFET, SMPS, 200V, 16A, 125W, <30/80ns	17p	TO-220				(BUZ 341, BUZ 350, 2SK851, 2SK901) ⁶
PRFZ 40	Phi	MOS-N-FET-e	VFET, SMPS, 50V, 51A, 125W, <25/70ns	17p	TO-220				STVHD 90, (BUZ 346, 2SK1379) ⁶
PRFZ 42	Phi	MOS-N-FET-e	VFET, SMPS, 50V, 46A, 125W, <25/70ns	17p	TO-220				STVHD 90, (BUZ 346, 2SK1379) ⁶
PS		Si-N-Darl	=2SD1511-S (SMD-Marking)	39	SOT-89				+2SD1511
PS		Si-N	=2SD1821-S (SMD-Marking)	35(2mm)	SOT-323				+2SD1821
PS		Si-N	=2SD2240-S (SMD-Marking)	35(1,6mm)	SS Mini				+2SD2240
PS		Si-N	=2SD814-S (SMD-Marking)	35	SOT-23				+2SD814
PS		Si-P	=KRA223S (SMD-Marking)	35	SOT-23				+KRA 223S
PSB 79 C30E-N		CMOS-IC	=PSB 79C30E-P: SMD		44-PLCC				-
PSB 79 C30E-P	Sie	CMOS-IC	Telecom, ISDN, IOM-2 Digital Subscr. Ctrl.(DSC/E)		40-DIP				-
PSB 2110-N		CMOS-IC	=PSB 2110-P: SMD		44-PLCC				-
PSB 2110-P	Sie	CMOS-IC	Telecom, ISDN Terminal Adaptor (ITAC)		40-DIP				-
PSB 2120-P	Sie	CMOS-IC	Telecom, ISDN Remote Power Controller (IRPC)		22-DIP				-
PSB 2121-P	Sie	CMOS-IC	Telecom, General Purpose Controller (GPCC)		16-DIP				-
PSB 2121-T		CMOS-IC	=PSB 2121-P: SMD		20-MDIP				-
PSB 2160-N		CMOS-IC	=PSB 2160-P: SMD		28-PLCC				-
PSB 2160-P	Sie	CMOS-IC	Telecom, Audio Ringing Codec Filter (ARCOFI)		24-DIP				-
PSB 3530	Sie	LIN-IC	Telecom, Subscriber Station Interface		28-DIC				SM 339
PSB 4500-P	Sie	LIN-IC	Telecom, Sprechkreis/Speech Circuit		20-DIP				-